

# Verification of Singulated HBM2 stacks with a KGS Test Cell

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## **Paper Discussion Outline**

#### Industry Need for High Performance HBM Memory

- Performance benefits and application drivers
- HBM process flow and critical test insertion point
- Known good stack die probing key challenges

#### Probe card design challenges: probing on micro-bump at <60um pitch</li>

- Design rules for high speed
- Space Transformation technology development

#### Direct on Micro-bump probing results

- Overdrive versus probe force & probe diameter discussion
- Ambient scrub mark pictures & result
- High temperature scrub mark & test result

#### Actual ATE Signal output/input performance on HBM2 device

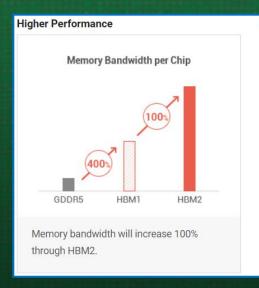
- Simulation vs Actual Measurement result @ 2Gbps
- 1ch drive vs 8ch simultaneous drive actual result
- 1.6GHz/3.2Gbps simulation result

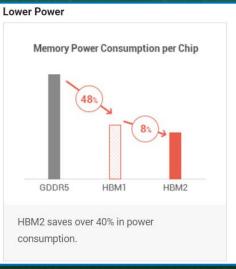
#### Proven benefits of this approach & Next Steps

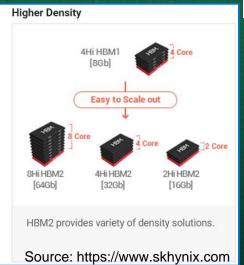
- Final product testing
- High temperature and High frequency

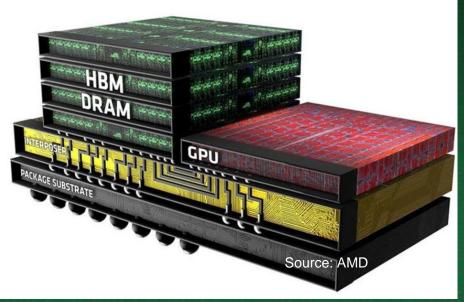
## HBM Addresses the Industry's Need for High Performance Memory

- Increased Bandwidth
- Lower Power Consumption
- Higher Density Package
  - HBM provide higher bandwidth than GDDR5 technology
  - 40% less power consumption
  - Smaller form factor with variety of density solutions





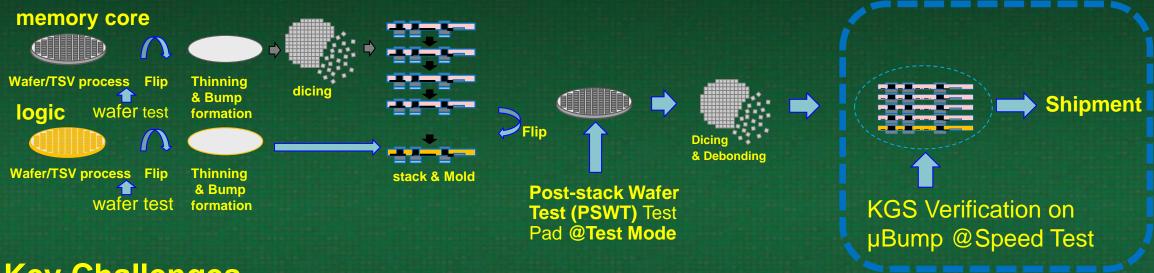




#### **Applications and drivers**

- Graphic card
- Server/Network
- Game Console
- High performance computing
- Personal Computer
- Artificial Intelligence

## **HBM Flow and KGSD Test Challenges**



## **Key Challenges**

- Handling of bare stack die
- Thermal movement
- Contact stability at elevated temperature
- Micro-bump "coining" behavior at high temp

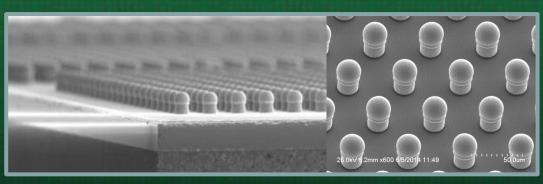
## **Known-Good-Stack Testing Goals**

- Contact all micro-bumps on HBM stacks to allow native mode functional and performance testing on all eight memory channels.
- Support at-speed testing > 2.4Gbps.
- Supports extreme temperature testing.
- Reliable contact to ~4,000 micro-bumps with a pitch of 55um.

## **Probe Card Design Requirement**

**JEDEC HBM2 Layout Configuration** 





### HBM Array Structure

- Total TSV Micro Bumps: 3990
  - 55µm Micro Bump Pitch
     (27.5 x 48um staggered)
- Total IO Micro Bumps: 1728
- Direct access micro bumps176
- Total Power Supplies: 3 1056
- Total ground Micro Bumps: 1030

#### Array size

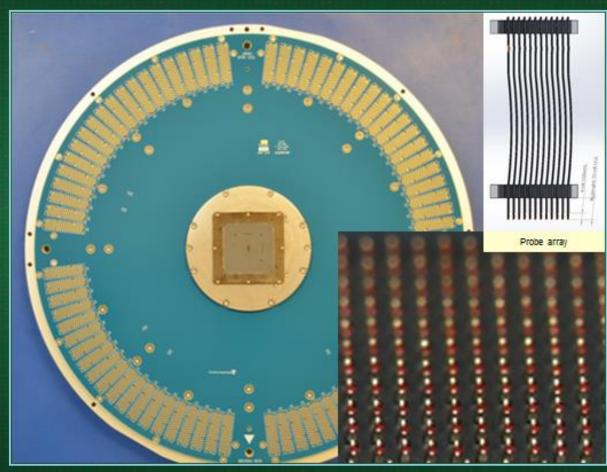
– 6022μm x 2832μm

#### Test requirement

- 2.133 Gb/s Functional test of the stack
- All 8 device channels

## Probe card design challenges

**Probing on TSV bump at 55um pitch** 



Actual FFI Apollo MF40 Probe Card

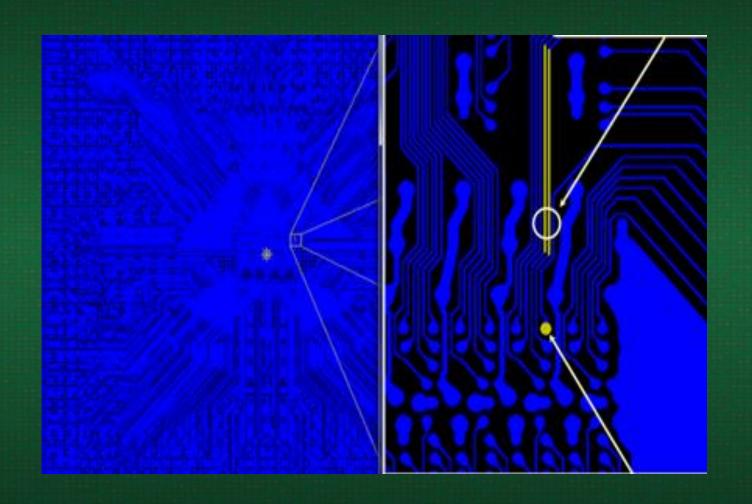
#### **FormFactor Solution**

- Apollo MF40 MEMs
  - High speed grid array application
  - 2Gbps on TSV Micro-bump

## **Challenges:**

- Design rules for high speed
  - SI simulation validation
  - Impedance control from LIF to Tip
- ST Trace geometry
  - Line & Space technology
  - Routing challenges
- ST Manufacturability

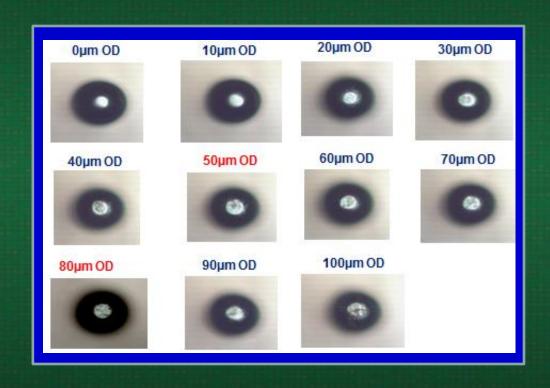
## **Space Transformation Design Challenges**

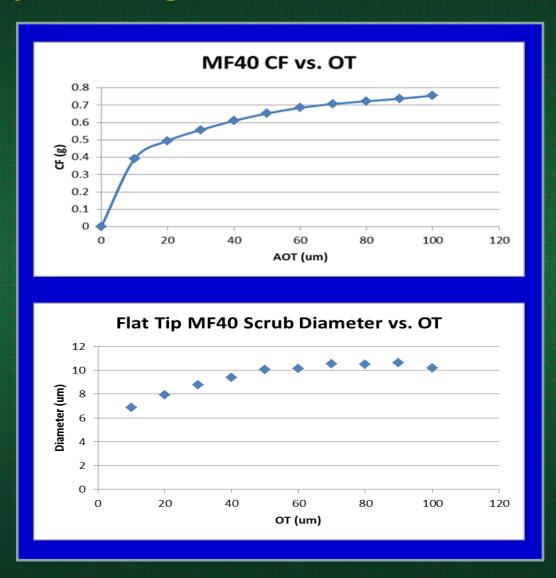


#### Small die size, high bump counts

- ~4000 traces in ~6x3mm
- FFI proprietary ST MLO fan-out design enabler
  - Pushing the MLO technology limit
  - Co-develop additional capability for high speed requirement
  - Line/space and layer count
- Impedance control optimization
  - Minimize voltage reflection & cross talk

## FFI MF40 Micro-Bump Probing Characteristics



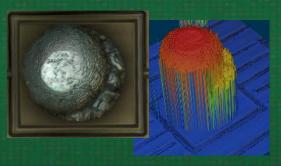


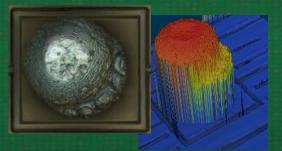
## **HBM2** Die Micro-bump Probing Results - Ambient

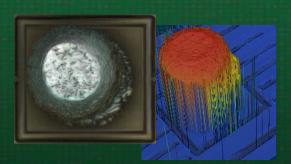
- We succeeded in contacting all I/O pins
- Ambient scrub mark pictures & result
  - Contact Time:6sec, Contact : 1 time vs 2 times
  - Contact Time:600sec, Contact : 1 time vs 2 times

The scrub becomes deeper as the number of contacts increases

The scrub becomes deeper as the test time becomes longer







Condition	T.T:6sec 1 time	T.T:6sec 2 times
Scrub depth[um]	0.87	1.72
Scrub diameter[um]	10.86	10.86

Condition	T.T:600sec 1 time	T.T:600sec 2 times
Scrub depth[um]	2.61	2.99
Scrub diameter[um]	14.81	15.04

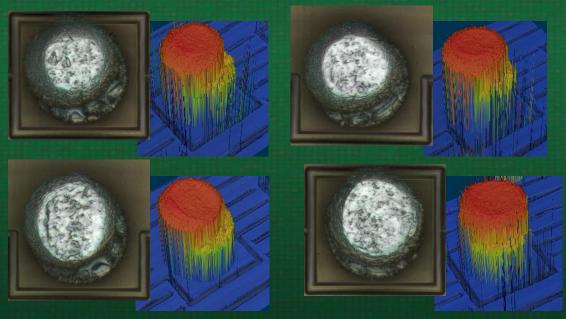
uBump Diameter: 25um
Over Drive : 60um
Temperature : Ambient

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## **HBM2** Die Micro-bump Probing Results – High Temperature

- We succeeded in contacting all I/O pins
- High temperature scrub mark & test result
  - Contact Time:6sec, Contact : 1 time vs 2 times
  - Contact Time:600sec, Contact: 1 time vs 2 times

The scrub becomes deeper as the temperature becomes higher



Condition	T.T:6sec 1 time	T.T:6sec 2 times
Scrub depth[um]	1.66	1.84
Scrub diameter[um]	14.34	16.07

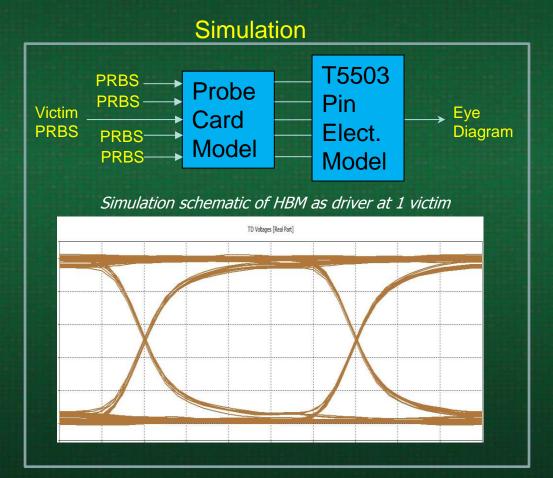
Condition	T.T:600sec 1 time	T.T:600sec 2 times
Scrub depth[um]	2.80	3.86
Scrub diameter[um]	17.06	18.71

uBump Diameter: 25um
Over Drive : 60um
Temperature : 105degC

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## Signal Output/Input Performance on HBM2 Die

- Simulation vs Actual Measurement result @ 2Gbps
  - The waveform is similar in simulation and actual measurement on HBM2 die
  - Strong eye-diagram performance correlation

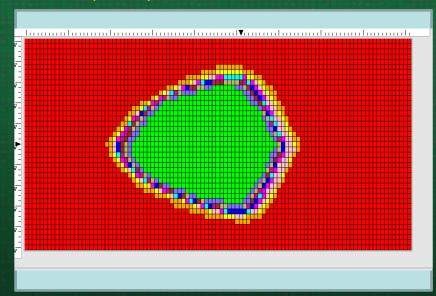


# **Actual Measurement** PRBS signal driver and T5503HS's comparator were terminated with $50\Omega$ .

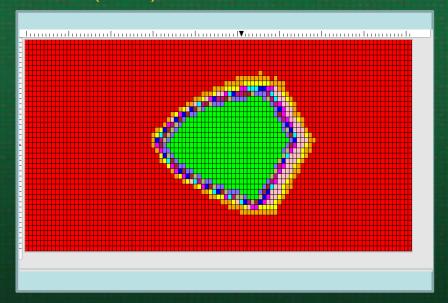
## Signal Output/Input Performance on HBM2 Die

- 1ch drive vs 8ch simultaneous drive actual result @ 2Gbps
  - With data activity on just one memory channel the output data eye width is quite large.
  - With data activity on all eight memory channels the output data eye shrinks.

#### Shmoo(Dout) 1ch meas. / 1ch drive

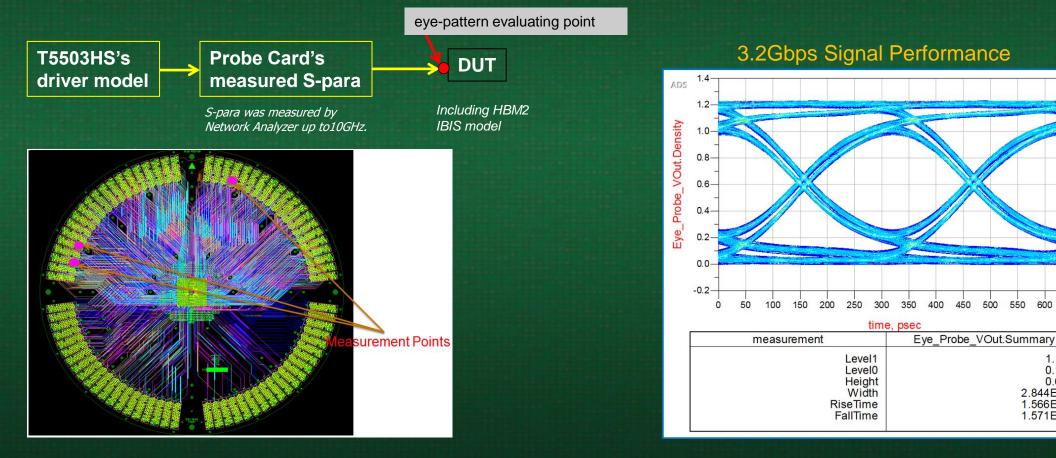


#### Shmoo(Dout) 1ch meas. / 8ch drives



## Signal Output/Input at Higher Frequency

- 1.6GHz/3.2Gbps simulation result
  - MF40 technology supports operating speed to 3.2Gb/s with additional design rules optimization
  - Strong simulation versus actual measurement result as validated through ATE at 2Gbps



0.134 0.656

2.844E-10 1.566E-10

1.571E-10

## **Benefit Summary**

- Working together as a team Advantest together with FormFactor developed a production worthy tool for confirming Known-Good Memory Stacks with ~4,000 microbumps and < 60um bump pitch.</li>
- The resulting design exceeded our design goals for probe force and CCC with a wide operational temperature range.
- The solution exceeded our high frequency goal demonstrating >3 Gbps performance.
- The solution contacts to all eight HBM channels simultaneously enabling native mode performance and functional testing of these complex devices.

## Acknowledgement

## **SK Hynix**

- Kim Wangki
- Seo JaeHyoung

#### **FormFactor Inc**

- Quay Nhin
- Hirofumi Nagata
- Uyen Nguyen
- Todd Swart

#### **Advantest**

- Toshiyuki Kiyokawa
- Dave Armstrong
- Masayoshi Ichikawa
- Tetsuo Shikata
- Koji Sakai
- Lee Kyungeul
- Kim Sangdeuk





